

Product data sheet

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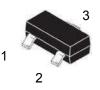
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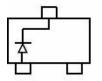


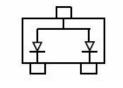
FEATURES

Extremely Fast Switching Speed

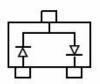


SOT-23









BAT54 MARKING: KL1

BAT54A MARKING: KL2

BAT54C MARKING: KL3

BAT54S MARKING: KL4

Maximum Ratings @T_A=25℃

Parameter	Symbol	Limits	Unit
Peak Repetitive Peak reverse voltage	V _{RRM}		
Working Peak Reverse Voltage	V _{RWM}	30	V
	VR		
Forward Continuous Current	I _{FM}	200	mA
Power Dissipation	PD	200	mW
Storage temperature	T _{STG}	-55-150	°C

Electrical Characteristics @T_A=25℃

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Reverse Breakdown Voltage	V _{(BR)R}	30			V	IR=100μA
	V _{F1}			0.24	V	I _F =0.1mA
Forward voltage	V _{F2}			0.32	V	I _F =1mA
	V _{F3}			0.40	V	I⊧=10mA
	V _{F4}			0.50	V	I⊧=30mA
	V _{F5}			1	V	I _F =100mA
Reverse current	I _R			2	μA	V _R =25V
Diode Capacitance	CD			10	pF	V _R =1V,f=1MHz
Reverse Recovery Time	t _{rr}			5	nS	I _F =I _R =10mA Irr=0.1XI _R ,R _L =100Ω

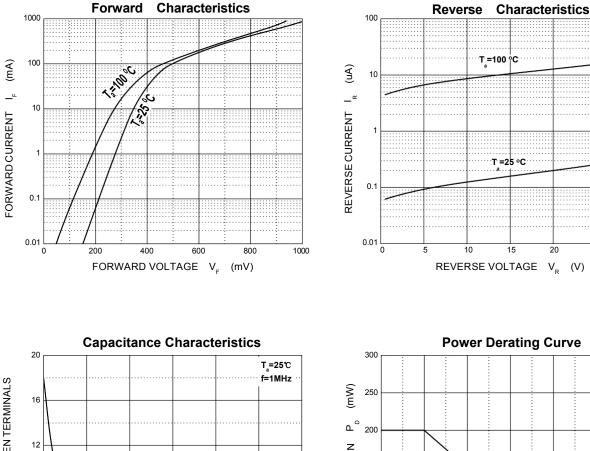




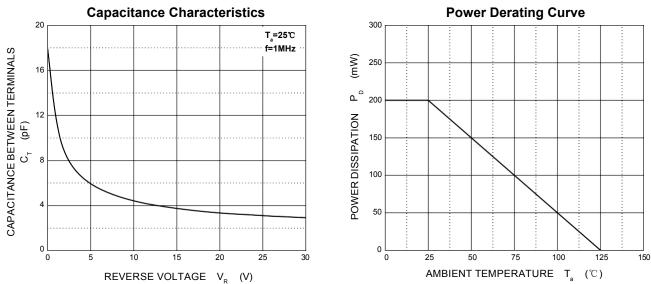
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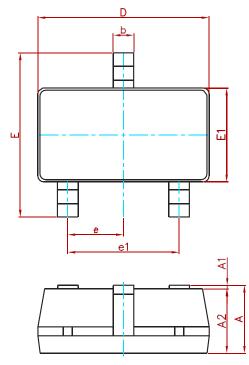
Typical Characteristics

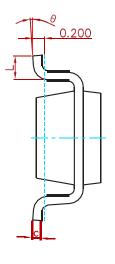




BAT54/A/C/S HF Semiconductor Compiance

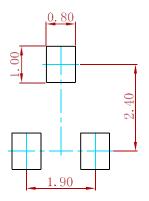
PACKAGE MECHANICAL DATA





Symbol	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E1	1.500	1.700	0.059	0.067	
E	2.650	2.950	0.104	0.116	
е	0.950(BSC)		0.037	(BSC)	
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
0	0°	8°	0°	8°	

Suggested Pad Layout



Note:

Controlling dimension: in millimeters.
General tolerance: ± 0.05mm.

3. The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
BAT54/A/C/S	SOT-23	3000





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